

# NCE N-Channel Enhancement Mode Power MOSFET

### Description

The NCE3080I uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

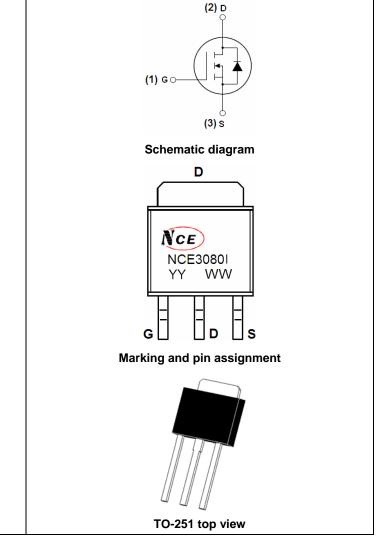
#### **General Features**

- V<sub>DS</sub> =30V,I<sub>D</sub> =80A
  R<sub>DS(ON)</sub> <6.5mΩ @ V<sub>GS</sub>=10V
  R<sub>DS(ON)</sub> < 10mΩ @ V<sub>GS</sub>=5V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

#### 100% UIS TESTED!



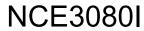
#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3080I	NCE3080I	TO-251	-	-	-

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	VDS	30	V	
Gate-Source Voltage	V <sub>GS</sub>	±20	V	
Drain Current-Continuous	Ι <sub>D</sub>	80	А	
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	50	А	
Pulsed Drain Current	I <sub>DM</sub>	170	А	
Maximum Power Dissipation	PD	83	W	
Derating factor		0.56	W/℃	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	150	mJ	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C	





#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)ReJC1.8°C/W
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### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter Symbol Conditio		Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)	· ·			•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1	1.5	3	V
Drain Course On State Desistance	P	$V_{GS}$ =10V, I <sub>D</sub> =30A	- 5.5 6.5 - 7.5 10		6.5	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =5V, I <sub>D</sub> =24A			10	
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =24A	20	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	2330	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =15V, $V_{GS}$ =0V,	-	460	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	230	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	20	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =10V,I <sub>D</sub> =30A	-	15	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =2.7 $\Omega$	-	60	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	10	-	nS
Total Gate Charge	Qg	V/ 40V/1 20A	-	51	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =10V,I <sub>D</sub> =30A,	-	14	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	11	-	nC
Drain-Source Diode Characteristics	· ·			•		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =24A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	80	А
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 80A	-	32	50	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	12	20	nC

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

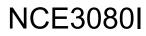
4. Guaranteed by design, not subject to production

**5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=15V,V<sub>G</sub>=10V,L=1mH, Rg=25 $\Omega$ 

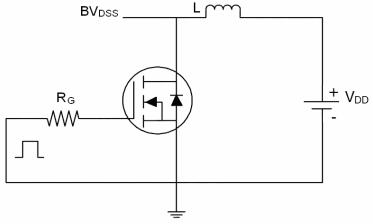


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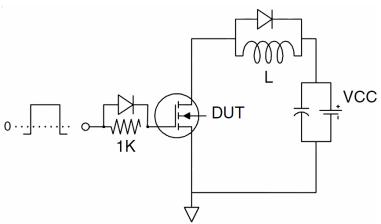
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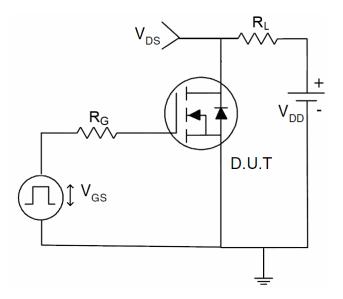
## Test Circuit 1) E<sub>AS</sub> Test Circuits



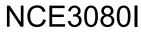
### 2) Gate Charge Test Circuit:



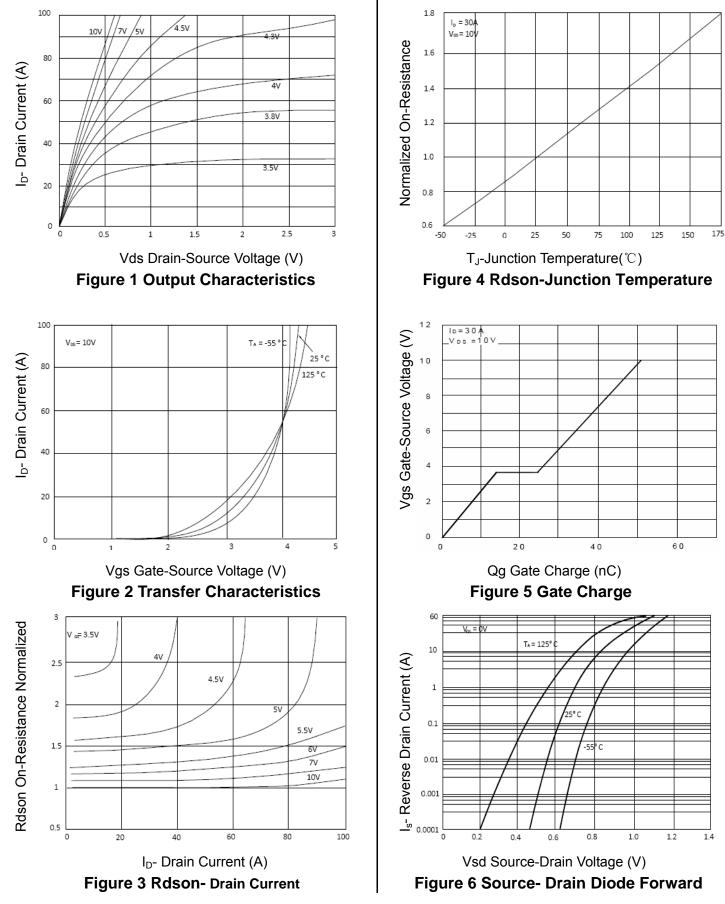
3) Switch Time Test Circuit:







## **Typical Electrical and Thermal Characteristics (Curves)**

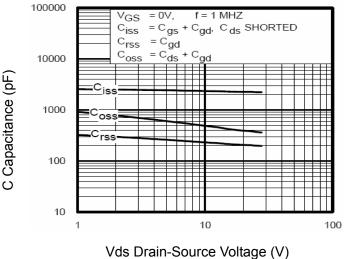


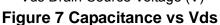


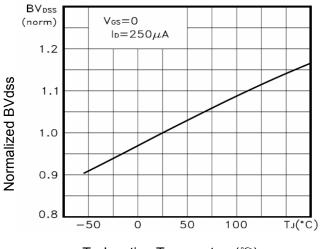
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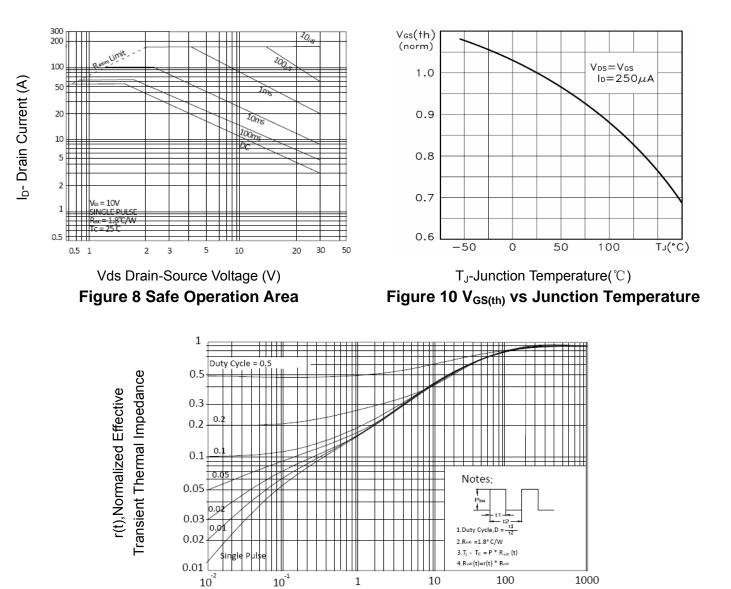
NCE3080I







TJ-Junction Temperature(℃) Figure 9 BV<sub>DSS</sub> vs Junction Temperature

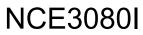


Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance

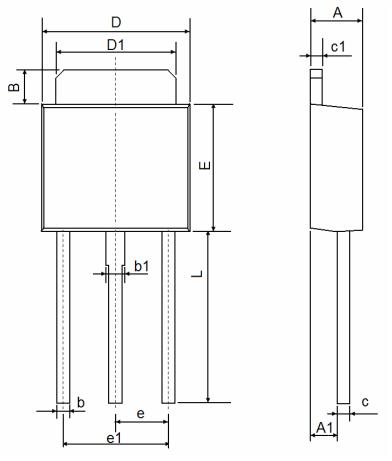


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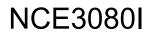
# TO-251 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	1.050	1.350	0.042	0.054	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
e	2.300 TYP.		0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	7.500	7.900	0.295	0.311	







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